## **Supplementary Information**

## Multi-spectral imaging with infrared sensitive organic light emitting diode

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## **Supplementary Figures**

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Figure S1. (a) Luminance-current density-voltage (L-I-V) characteristics and (b) current efficiencies plot of the transparent OLED with the Mg:Ag/Alq<sub>3</sub> transparent top cathode.



Figure S2. Schematic energy band diagrams of the IR sensitive OLED in the IR illumination.



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**Figure S3.** (**a**) the transparency spectra of the ITO anode as a control bottom electrode, the IPVM/ITO anode as a IR transparent, visible reflective bottom electrode, and the Mg:Ag/Alq<sub>3</sub> cathode as a visible transparent top electrode, and (**b**) L-I-V characteristics and (**c**) current efficiencies plot of the top emitting OLED with the IPVM/ITO bottom electrode and the Mg:Ag/Alq<sub>3</sub> top electrodes.



Figure S4. Comparison of spectral p-p conversion efficiencies of reflective, transparent, and IPVM IR-OLEDs with the SnPc: $C_{60}$  IR sensitizer and the absorption spectrum of the SnPc: $C_{60}$  IR sensitizing film.



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**Figure S5.** (a) L-V characteristics and (b) spectral p-p conversion efficiencies of the flexible IR-OLEDs (insert - the image of a flexible device).



**Figure S6.** Schematic diagram of the monocular direct view IR imager with the transparent IR-OLEDs.



Figure S7. Absorption spectra of PbS nanocrystals.